

DIODE TRIODE

Medium-gain triode for use as A.F. voltage amplifier, combined with a single diode for signal or A.V.C. rectification.

DAC32

FILAMENT

This valve is suitable for D.C. operation only.

V_f	1.4	V
I_f	0.05	A

CAPACITANCES

C_{in}	1.3	μF
C_{out}	6.0	μF
C_{a-g}	1.0	μF
C_{ad-f}	3.2	μF
C_{ad-g}	0.002	μF
C_{ad-at}	0.2	μF

TYPICAL OPERATING CONDITIONS

Triode Section as Class "A" Amplifier

V_a	90	V
V_g	0	V
I_a	0.15	mA
μ	65	
r_a	240,000	ohms
g_m	275	$\mu A/V$

Diode Section

The diode anode is located at the negative end of the filament.

LIMITING VALUE

V_a max.	110	V
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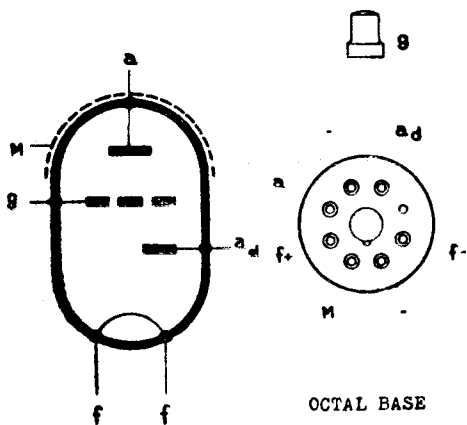


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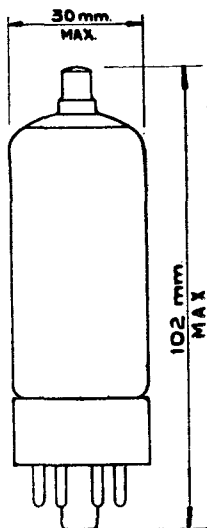
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rectification.*

ARRANGEMENT OF ELECTRODES
AND BASE CONNECTIONS



OCTAL BASE

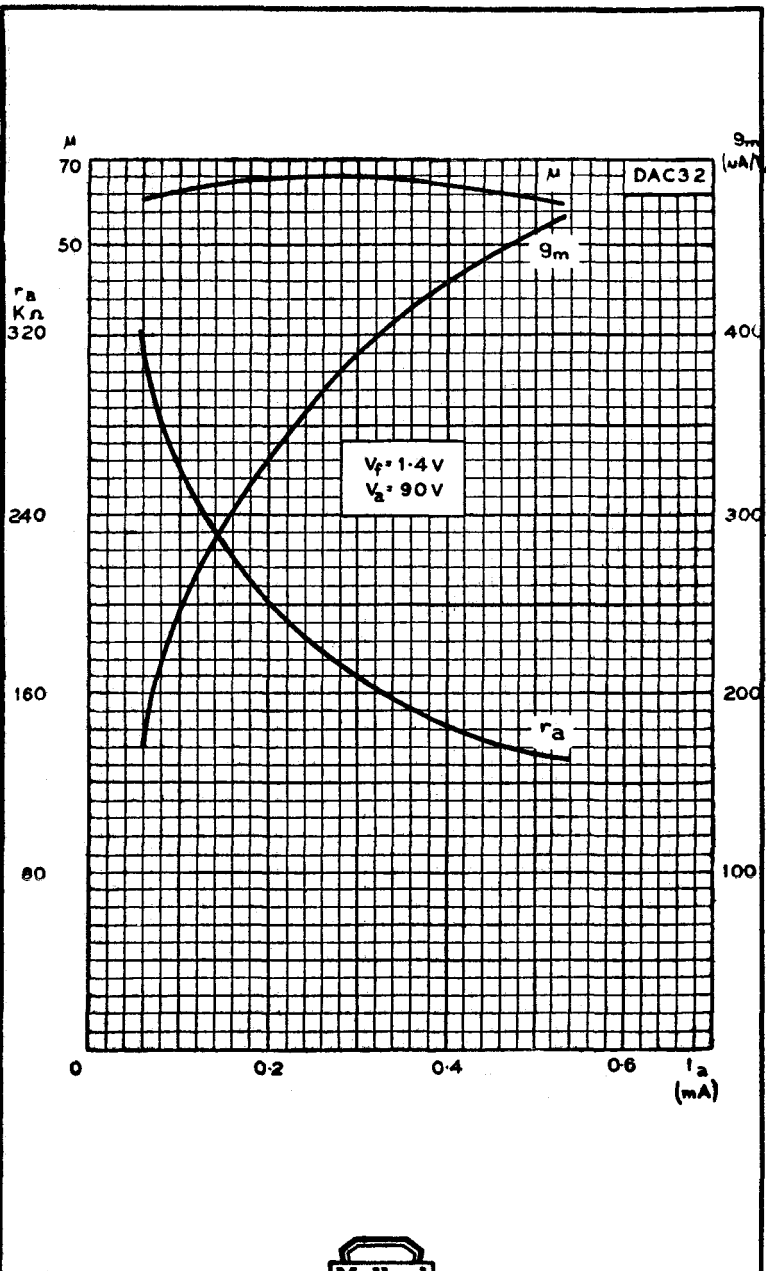
DIMENSIONS



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